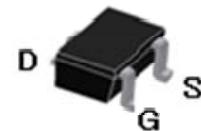
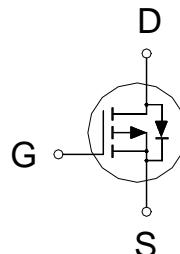


P-Channel Logic Level Enhancement Mode Field Effect Transistor

Product Summary:

BV <sub>DSS</sub>	-30V
R <sub>DSON</sub> (MAX.)	85mΩ
I <sub>D</sub>	-3.6A



Pb-Free Lead Plating & Halogen Free



**ABSOLUTE MAXIMUM RATINGS (T<sub>A</sub> = 25 °C Unless Otherwise Noted)**

PARAMETERS/TEST CONDITIONS		SYMBOL	LIMITS	UNIT
Gate-Source Voltage		V <sub>GS</sub>	±20	V
Continuous Drain Current	T <sub>A</sub> = 25 °C	I <sub>D</sub>	-3.6	A
	T <sub>A</sub> = 70 °C		-2.5	
Pulsed Drain Current <sup>1</sup>		I <sub>DM</sub>	-14	
Power Dissipation	T <sub>A</sub> = 25 °C	P <sub>D</sub>	1.04	W
	T <sub>A</sub> = 70 °C		0.66	
Operating Junction & Storage Temperature Range		T <sub>j</sub> , T <sub>stg</sub>	-55 to 150	°C

**THERMAL RESISTANCE RATINGS**

THERMAL RESISTANCE	SYMBOL	TYPICAL	MAXIMUM	UNIT
Junction-to-Ambient <sup>3</sup>	R <sub>θJA</sub> (T ≤ 10sec)		83	°C / W
	R <sub>θJA</sub> (Steady State)		120	

<sup>1</sup>Pulse width limited by maximum junction temperature.

<sup>2</sup>Duty cycle ≤ 1%

<sup>3</sup>The device mounted on a 1 in<sup>2</sup> pad of 2 oz copper.

ELECTRICAL CHARACTERISTICS ( $T_J = 25^\circ\text{C}$ , Unless Otherwise Noted)

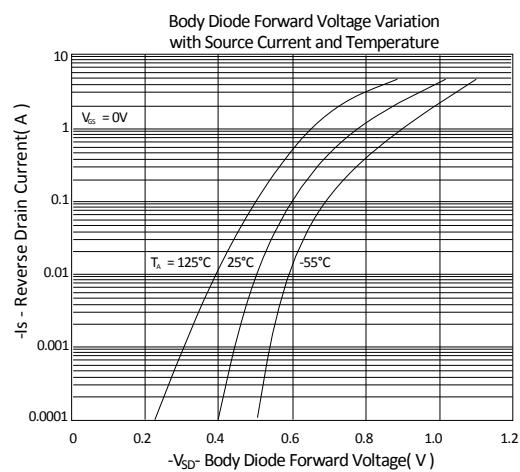
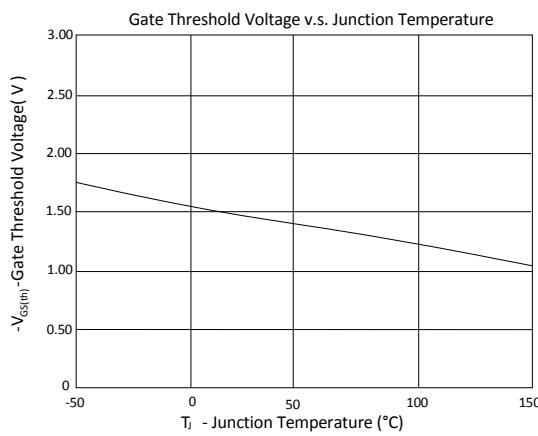
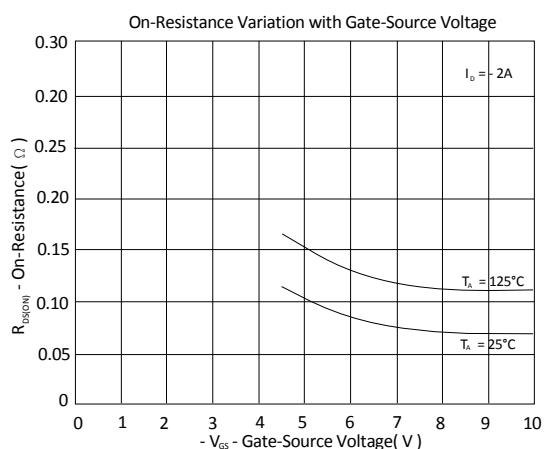
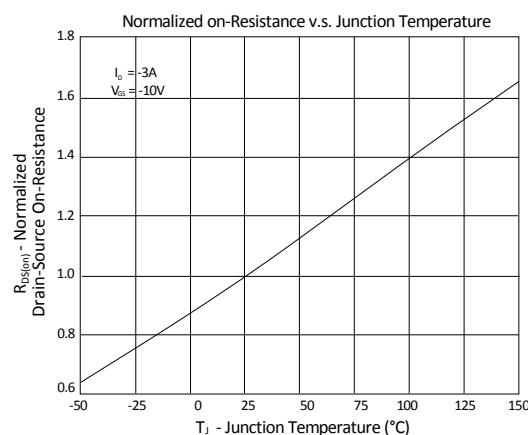
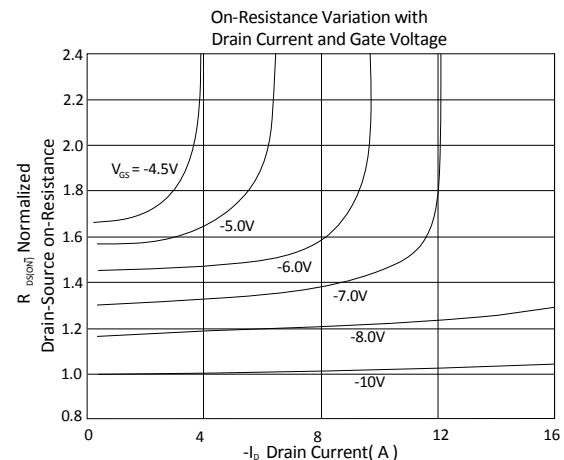
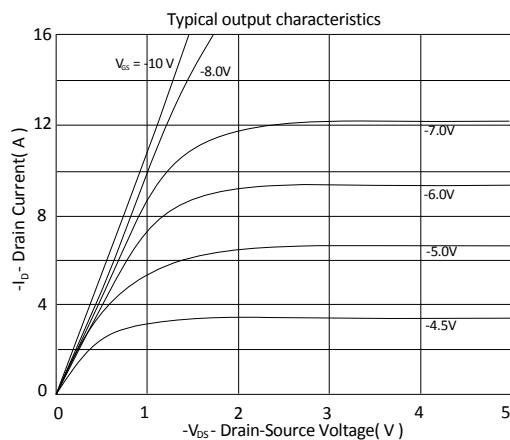
PARAMETER	SYMBOL	TEST CONDITIONS	LIMITS			UNIT
			MIN	TYP	MAX	
STATIC						
Drain-Source Breakdown Voltage	$V_{(\text{BR})\text{DSS}}$	$V_{\text{GS}} = 0\text{V}, I_D = -250\mu\text{A}$	-30			V
Gate Threshold Voltage	$V_{\text{GS}(\text{th})}$	$V_{\text{DS}} = V_{\text{GS}}, I_D = -250\mu\text{A}$	-1	-1.5	-3	
Gate-Body Leakage	$I_{\text{GSS}}$	$V_{\text{DS}} = 0\text{V}, V_{\text{GS}} = \pm 20\text{V}$			$\pm 100$	nA
Zero Gate Voltage Drain Current	$I_{\text{DSS}}$	$V_{\text{DS}} = -24\text{V}, V_{\text{GS}} = 0\text{V}$			-1	$\mu\text{A}$
		$V_{\text{DS}} = -20\text{V}, V_{\text{GS}} = 0\text{V}, T_J = 125^\circ\text{C}$			-10	
On-State Drain Current <sup>1</sup>	$I_{\text{D}(\text{ON})}$	$V_{\text{DS}} = -5\text{V}, V_{\text{GS}} = -10\text{V}$	-3.6			A
Drain-Source On-State Resistance <sup>1</sup>	$R_{\text{DS}(\text{ON})}$	$V_{\text{GS}} = -10\text{V}, I_D = -3.6\text{A}$		75	85	$\text{m}\Omega$
		$V_{\text{GS}} = -4.5\text{V}, I_D = -2.5\text{A}$		125	145	
Forward Transconductance <sup>1</sup>	$g_{\text{fs}}$	$V_{\text{DS}} = -5\text{V}, I_D = -3\text{A}$		5		S
DYNAMIC						
Input Capacitance	$C_{\text{iss}}$	$V_{\text{GS}} = 0\text{V}, V_{\text{DS}} = -15\text{V}, f = 1\text{MHz}$		337		$\text{pF}$
Output Capacitance	$C_{\text{oss}}$			48		
Reverse Transfer Capacitance	$C_{\text{rss}}$			36		
Total Gate Charge <sup>1,2</sup>	$Q_g$	$V_{\text{DS}} = -10\text{V}, V_{\text{GS}} = -10\text{V}, I_D = -3\text{A}$		5.1		$\text{nC}$
Gate-Source Charge <sup>1,2</sup>	$Q_{\text{gs}}$			0.9		
Gate-Drain Charge <sup>1,2</sup>	$Q_{\text{gd}}$			1.1		
Turn-On Delay Time <sup>1,2</sup>	$t_{\text{d}(\text{on})}$	$V_{\text{DS}} = -10\text{V}, I_D = -1\text{A}, V_{\text{GS}} = -10\text{V}, R_{\text{GS}} = 6\Omega$		15		$\text{nS}$
Rise Time <sup>1,2</sup>	$t_r$			30		
Turn-Off Delay Time <sup>1,2</sup>	$t_{\text{d}(\text{off})}$			35		
Fall Time <sup>1,2</sup>	$t_f$			30		
SOURCE-DRAIN DIODE RATINGS AND CHARACTERISTICS ( $T_c = 25^\circ\text{C}$ )						
Continuous Current	$I_S$				-2	$\text{A}$
Pulsed Current <sup>3</sup>	$I_{\text{SM}}$				-8	
Forward Voltage <sup>1</sup>	$V_{\text{SD}}$	$I_F = I_S, V_{\text{GS}} = 0\text{V}$			1.2	V

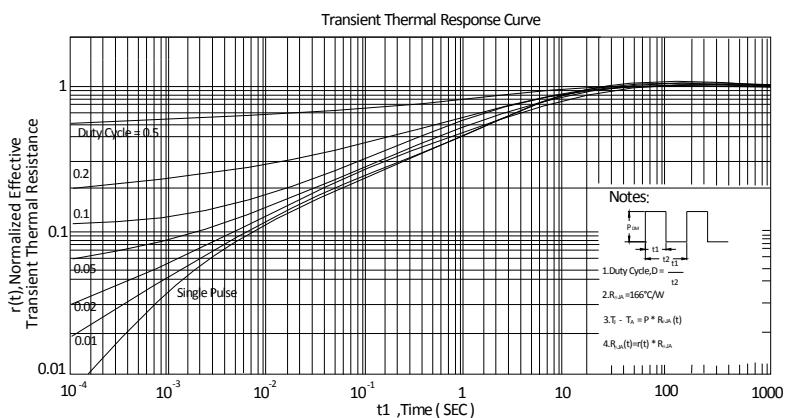
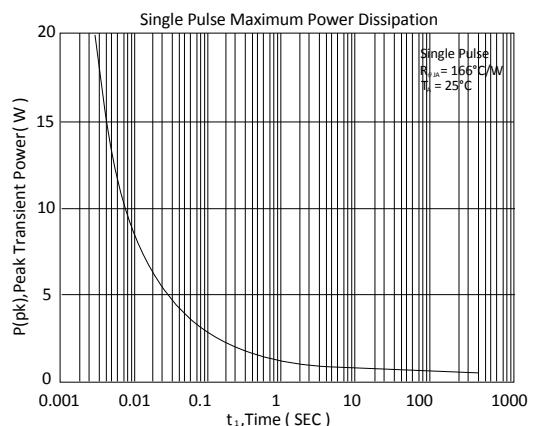
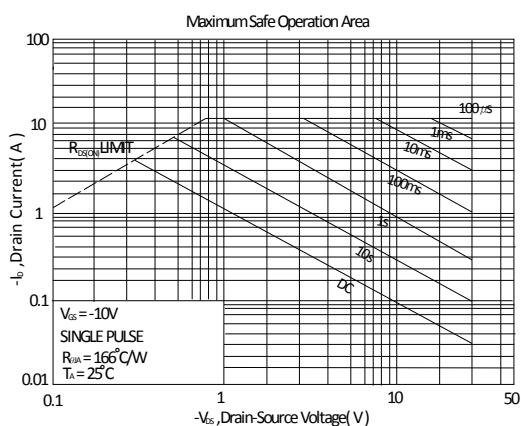
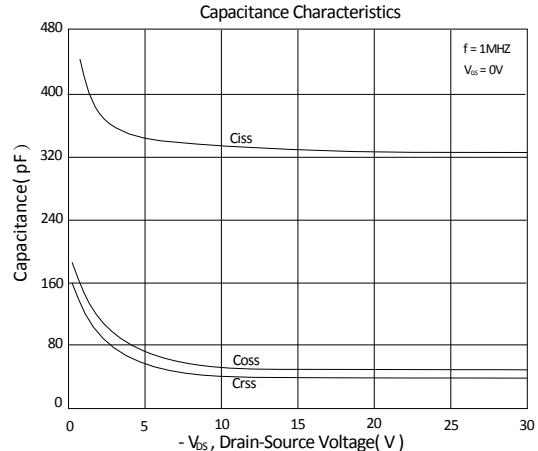
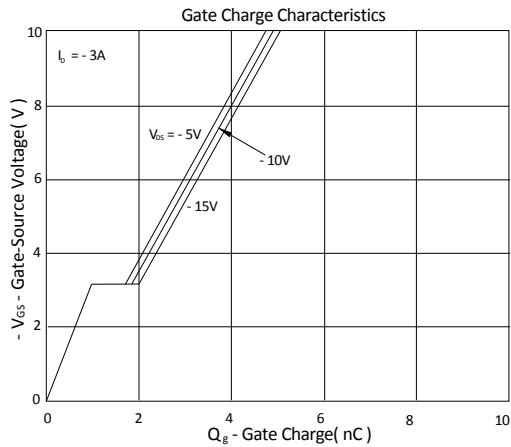
<sup>1</sup>Pulse test : Pulse Width  $\leq 300 \mu\text{sec}$ , Duty Cycle  $\leq 2\%$ .

<sup>2</sup>Independent of operating temperature.

<sup>3</sup>Pulse width limited by maximum junction temperature.

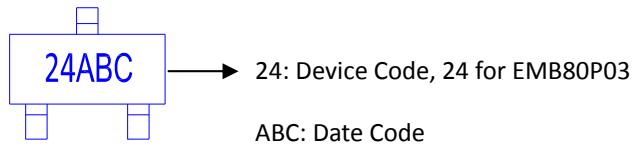
## TYPICAL CHARACTERISTICS



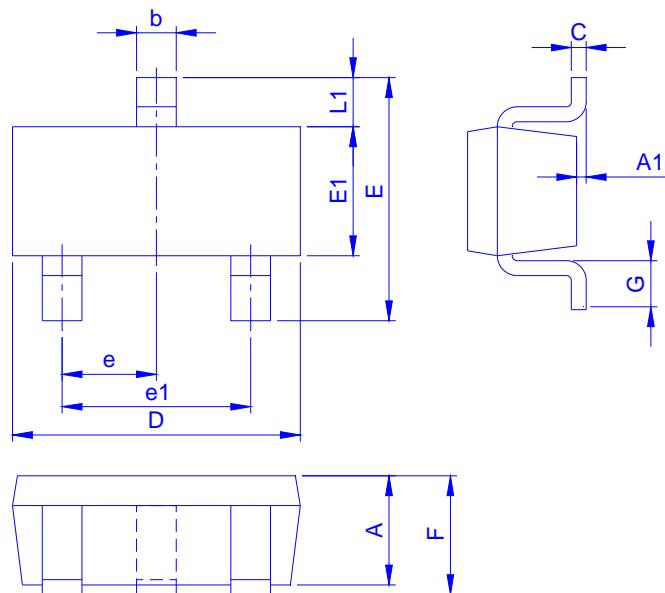


Ordering & Marking Information:

Device Name: EMB80P03JS for SOT-23



Outline Drawing



Dimension in mm

Dimension	A	A1	b	C	D	E	E1	e	e1	F	G	L1
Min.	0.70	0	0.3	0.08	2.80	2.25	1.2	0.90		0.80	0.3	0.50
Typ.					2.90			0.95	1.9			
Max.	1.15	0.1	0.5	0.20	3.02	3.00	1.7	1.00		1.25	0.6	0.75

Footprint

